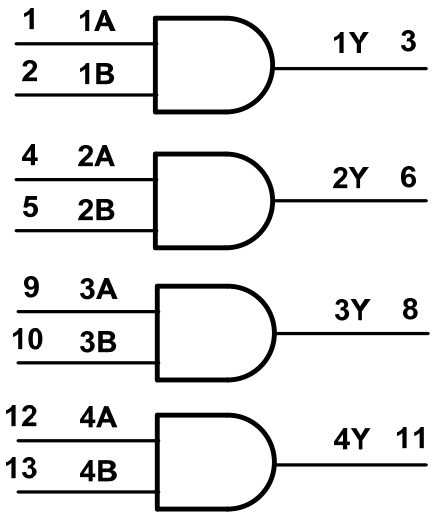
Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	V_{CC}	Supply Voltage

Logic Diagram



Function Table

Inputs		Output
A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +7.0	V
V_I	Input Voltage Range (Note 5)	-0.5 to +7.0	V
I_{IK}	Input Clamp Current V_I < -0.5V or Vi> V_{CC} +0.5V	±20	mA
I_{OK}	Output Clamp Current V_O < -0.5V or V_O > V_{CC} +0.5V	±20	mA
I_O	Continuous output current -0.5V < V_O V_{CC} +0.5V	+/- 25	mA
I_{CC}	Continuous current through V_{CC}	50	mA
I_{GND}	Continuous current through GND	-50	mA
T_J	Operating Junction Temperature	-40 to +150	°C
T_{STG}	Storage Temperature	-65 to +150	°C
P_{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
5. Input Voltage cannot exceed V_{CC} to the extent the Maximum clamp current is exceeded

Recommended Operating Conditions (Note 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply Voltage		2.0	6.0	V
V_I	Input Voltage		0	V_{CC}	V
V_O	Output Voltage		0	V_{CC}	V
Δt/ΔV	Input Transition Rise or Fall Rate	V_{CC} = 2.0V	—	625	ns/V
		V_{CC} = 4.5V	—	140	
		V_{CC} = 6.0V	—	85	
T_A	Operating Free-Air Temperature		-40	+125	°C

Note: 6. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V_{CC}	T_A = -40°C to +85°C		T_A = -40°C to +125°C		Unit
				Min	Max	Min	Max	
V_{IH}	High-level Input Voltage		2.0V	1.5	—	1.5	—	V
			4.5V	3.15	—	3.15	—	
			6.0V	4.2	—	4.2	—	
V_{IL}	Low-level Input Voltage		2.0V	—	0.5	—	0.5	V
			4.5V	—	1.35	—	1.35	
			6.0V	—	1.8	—	1.8	
V_{OH}	High-level Output Voltage	I_{OH} = -20μA	2.0V	1.9	—	1.9	—	V
		I_{OH} = -20μA	4.5V	4.4	—	4.4	—	
		I_{OH} = -20μA	6.0V	5.9	—	5.9	—	
		I_{OH} = -4.0mA	4.5V	3.84	—	3.7	—	
		I_{OH} = -5.2mA	6.0V	5.34	—	5.2	—	
V_{OL}	Low-level Output Voltage	I_{OL} = 20μA	2.0V	—	0.1	—	0.1	V
		I_{OL} = 20μA	4.5V	—	0.1	—	0.1	
		I_{OL} = 20μA	6.0V	—	0.1	—	0.1	
		I_{OL} = 4mA	4.5V	—	0.33	—	0.44	
		I_{OL} = 5.2 mA	6.0V	—	0.33	—	0.44	
I_I	Input Current	V_I =GND to 5.5V	6.0V	—	± 1	—	± 1	μA
I_{CC}	Supply Current	V_I = GND or V_{CC}, I_O = 0	6.0V	—	20	—	40	μA

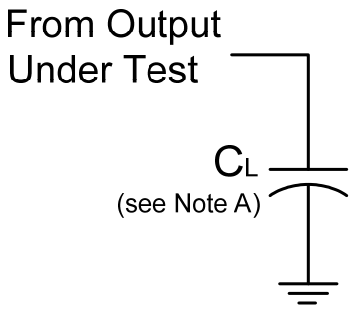
Switching Characteristics

Symbol	Parameter	Test Conditions	Vcc	T_A = +25°C			-40°C to +85°C	-40°C to +125°C	Unit
				Min	Typ.	Max	Max	Max	
t_{PD}	Propagation Delay A_N to Y_N	Figure 1 C_L = 50pF	2.0V	—	25	90	115	125	ns
			4.5V	—	9	18	23	27	
			6.0V	—	7	15	20	23	
t_t	Transition Time	Figure 1 C_L = 50pF	2.0V	—	19	75	95	110	ns
			4.5V	—	7	15	19	22	
			6.0V	—	6	13	16	19	

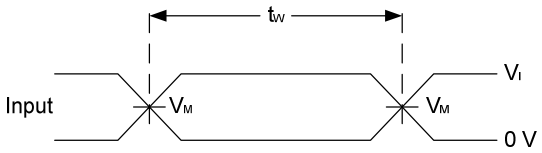
Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V_{CC} = 6V	Unit
			Typ	
C_{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	20	pF
C_I	Input Capacitance	V_I = V_{CC} – or GND	4	pF

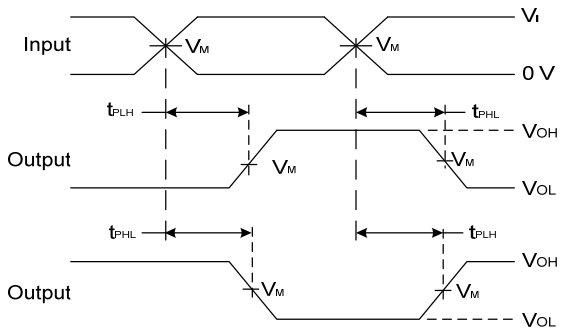
Parameter Measurement Information



V_{CC}	Inputs		V_M	C_L
	V_I	t_r/t_f		
2.0V to 6.0V	V_{CC}	6ns	$V_{CC}/2$	15pF,50pF



Voltage Waveform
Pulse Duration

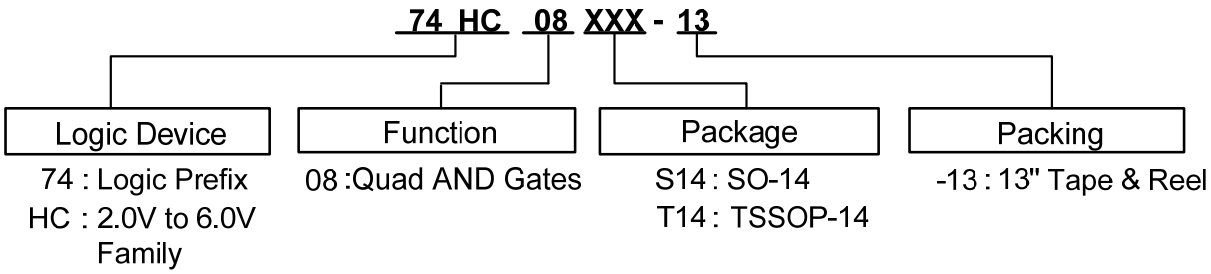


Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 1 MHz
C. Inputs are measured separately one transition per measurement
D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1 Load Circuit and Voltage Waveforms

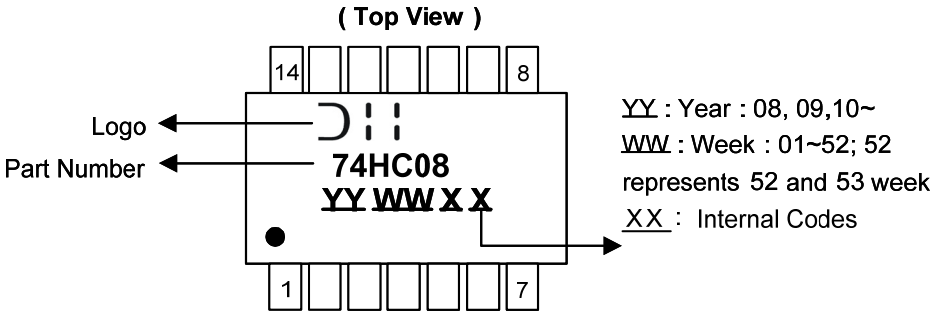
Ordering Information



Device	Package Code	Packaging	7" Tape and Reel	
			Quantity	Part Number Suffix
74HC08S14-13	S14	SO-14	2500/Tape & Reel	-13
74HC08T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Marking Information

(1) SO-14, TSSOP-14

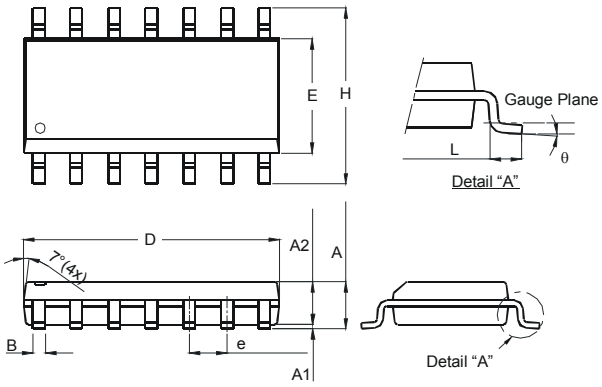


Part Number	Package
74HC08S14	SO-14
74HC08T14	TSSOP-14

Package Outline Dimensions (All dimensions in mm.)

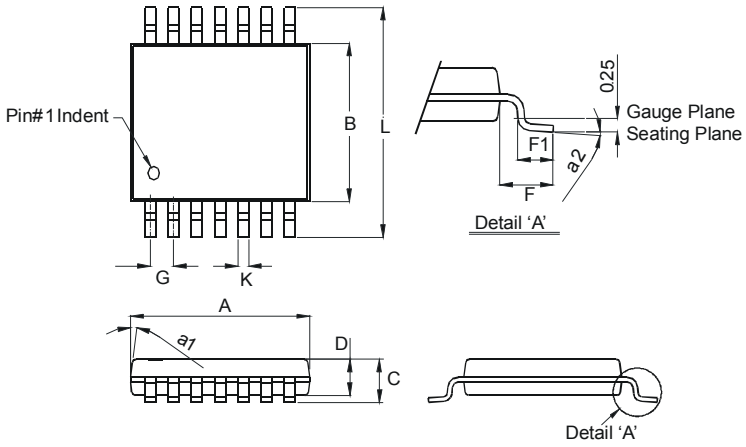
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



SO-14		
Dim	**Min**	**Max**
A	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
B	0.33	0.51
D	8.53	8.74
E	3.80	3.99
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14

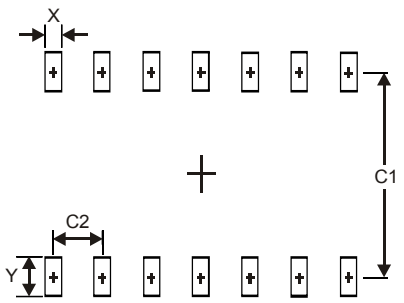


TSSOP-14		
Dim	**Min**	**Max**
a1	7° (4X)	
a2	0°	8°
A	4.9	5.10
B	4.30	4.50
C	—	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

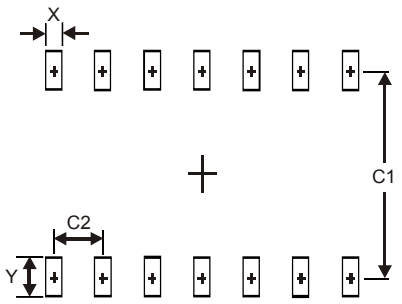
Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Y	1.50
C1	5.4
C2	1.27

Suggested Pad Layout (cont.)

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65